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#### Understanding <u>Embedded - FPGAs (Field</u> <u>Programmable Gate Array)</u>

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

#### **Applications of Embedded - FPGAs**

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details	
Product Status	Active
Number of LABs/CLBs	264
Number of Logic Elements/Cells	2112
Total RAM Bits	75776
Number of I/O	104
Number of Gates	-
Voltage - Supply	1.14V ~ 1.26V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 100°C (TJ)
Package / Case	132-LFBGA, CSPBGA
Supplier Device Package	132-CSPBGA (8x8)
Purchase URL	https://www.e-xfl.com/product-detail/lattice-semiconductor/lcmxo2-2000ze-1mg132i

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Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong



### Table 1-1. MachXO2™ Family Selection Guide

LUTs				7020400	702-1200	702-12000	702-2000	702-20000	XU2-4000	XU2-7000
2010		256	640	640	1280	1280	2112	2112	4320	6864
Distributed RAM (kbi	ts)	2	5	5	10	10	16	16	34	54
EBR SRAM (kbits)		0	18	64	64	74	74	92	92	240
Number of EBR SRA kbits/block)	M Blocks (9	0	2	7	7	8	8	10	10	26
UFM (kbits)		0	24	64	64	80	80	96	96	256
Device Options:	HC <sup>2</sup>	Yes	Yes	Yes	Yes	Yes	Yes	Yes	Yes	Yes
	HE <sup>3</sup>						Yes	Yes	Yes	Yes
	ZE <sup>4</sup>	Yes	Yes		Yes		Yes		Yes	Yes
Number of PLLs		0	0	1	1	1	1	2	2	2
Hardened I2C	12C	2	2	2	2	2	2	2	2	2
Functions:	1 (kbits)       2       5       5       10       10       16       16       16       34       54         SRAM Blocks (9       0       2       7       7       8       8       10       10       26         SRAM Blocks (9       0       2       7       7       8       8       10       10       26         M C <sup>2</sup> Yes       Yes	1								
		1	1	1	1	1	1	1	1	1
Packages						ю				
25-ball WLCSP⁵ (2.5 mm x 2.5 mm, 0	.4 mm)				18					
32 QFN <sup>6</sup> (5 mm x 5 mm, 0.5 m	nm)	21			21					
48 QFN <sup>8, 9</sup> (7 mm x 7 mm, 0.5 n	וm)	40	40							
49-ball WLCSP⁵ (3.2 mm x 3.2 mm, 0	.4 mm)						38			
64-ball ucBGA (4 mm x 4 mm, 0.4 m	וm)	44								
84 QFN <sup>7</sup> (7 mm x 7 mm, 0.5 m	וm)								68	
100-pin TQFP (14 mm x 14 mm)		55	78		79		79			
132-ball csBGA (8 mm x 8 mm, 0.5 m	וm)	55	79		104		104		104	
144-pin TQFP (20 mm x 20 mm)				107	107		111		114	114
184-ball csBGA <sup>7</sup> (8 mm x 8 mm, 0.5 m	וm)								150	
256-ball caBGA (14 mm x 14 mm, 0.8	3 mm)						206		206	206
256-ball ftBGA (17 mm x 17 mm, 1.0	) mm)					206	206		206	206
332-ball caBGA (17 mm x 17 mm, 0.8	3 mm)								274	278
484-ball ftBGA (23 mm x 23 mm, 1.0	) mm)							278	278	334

1. Ultra high I/O device.

2. High performance with regulator – VCC = 2.5 V, 3.3 V

3. High performance without regulator  $-V_{CC} = 1.2 V$ 4. Low power without regulator  $-V_{CC} = 1.2 V$ 5. WLCSP package only available for ZE devices.

6. 32 QFN package only available for HC and ZE devices.

7. 184 csBGA package only available for HE devices.

8. 48-pin QFN information is 'Advanced'.

9. 48 QFN package only available for HC devices.



### Figure 2-5. Primary Clocks for MachXO2 Devices



Primary clocks for MachXO2-640U, MachXO2-1200/U and larger devices.

Note: MachXO2-640 and smaller devices do not have inputs from the Edge Clock Divider or PLL and fewer routing inputs. These devices have 17:1 muxes instead of 27:1 muxes.

Eight secondary high fanout nets are generated from eight 8:1 muxes as shown in Figure 2-6. One of the eight inputs to the secondary high fanout net input mux comes from dual function clock pins and the remaining seven come from internal routing. The maximum frequency for the secondary clock network is shown in MachXO2 External Switching Characteristics table.



#### Figure 2-8. sysMEM Memory Primitives



#### Table 2-6. EBR Signal Descriptions

Port Name	Description	Active State
CLK	Clock	Rising Clock Edge
CE	Clock Enable	Active High
OCE <sup>1</sup>	Output Clock Enable	Active High
RST	Reset	Active High
BE <sup>1</sup>	Byte Enable	Active High
WE	Write Enable	Active High
AD	Address Bus	—
DI	Data In	—
DO	Data Out	—
CS	Chip Select	Active High
AFF	FIFO RAM Almost Full Flag	—
FF	FIFO RAM Full Flag	—
AEF	FIFO RAM Almost Empty Flag	—
EF	FIFO RAM Empty Flag	—
RPRST	FIFO RAM Read Pointer Reset	—

1. Optional signals.

2. For dual port EBR primitives a trailing 'A' or 'B' in the signal name specifies the EBR port A or port B respectively.

3. For FIFO RAM mode primitive, a trailing 'R' or 'W' in the signal name specifies the FIFO read port or write port respectively.

4. For FIFO RAM mode primitive FULLI has the same function as CSW(2) and EMPTYI has the same function as CSR(2).

5. In FIFO mode, CLKW is the write port clock, CSW is the write port chip select, CLKR is the read port clock, CSR is the read port chip select, ORE is the output read enable.



## **Output Register Block**

The output register block registers signals from the core of the device before they are passed to the sysIO buffers.

### Left, Top, Bottom Edges

In SDR mode, D0 feeds one of the flip-flops that then feeds the output. The flip-flop can be configured as a D-type register or latch.

In DDR generic mode, D0 and D1 inputs are fed into registers on the positive edge of the clock. At the next falling edge the registered D1 input is registered into the register Q1. A multiplexer running off the same clock is used to switch the mux between the outputs of registers Q0 and Q1 that will then feed the output.

Figure 2-14 shows the output register block on the left, top and bottom edges.

Figure 2-14. MachXO2 Output Register Block Diagram (PIO on the Left, Top and Bottom Edges)



### **Right Edge**

The output register block on the right edge is a superset of the output register on left, top and bottom edges of the device. In addition to supporting SDR and Generic DDR modes, the output register blocks for PIOs on the right edge include additional logic to support DDR-memory interfaces. Operation of this block is similar to that of the output register block on other edges.

In DDR memory mode, D0 and D1 inputs are fed into registers on the positive edge of the clock. At the next falling edge the registered D1 input is registered into the register Q1. A multiplexer running off the DQSW90 signal is used to switch the mux between the outputs of registers Q0 and Q1 that will then feed the output.

Figure 2-15 shows the output register block on the right edge.



MachXO2-640U, MachXO2-1200/U, MachXO2-2000/U, MachXO2-4000 and MachXO2-7000 devices contain three types of sysIO buffer pairs.

### 1. Left and Right sysIO Buffer Pairs

The sysIO buffer pairs in the left and right banks of the device consist of two single-ended output drivers and two single-ended input buffers (for ratioed inputs such as LVCMOS and LVTTL). The I/O pairs on the left and right of the devices also have differential and referenced input buffers.

### 2. Bottom sysIO Buffer Pairs

The sysIO buffer pairs in the bottom bank of the device consist of two single-ended output drivers and two single-ended input buffers (for ratioed inputs such as LVCMOS and LVTTL). The I/O pairs on the bottom also have differential and referenced input buffers. Only the I/Os on the bottom banks have programmable PCI clamps and differential input termination. The PCI clamp is enabled after  $V_{CC}$  and  $V_{CCIO}$  are at valid operating levels and the device has been configured.

### 3. Top sysIO Buffer Pairs

The sysIO buffer pairs in the top bank of the device consist of two single-ended output drivers and two singleended input buffers (for ratioed inputs such as LVCMOS and LVTTL). The I/O pairs on the top also have differential and referenced I/O buffers. Half of the sysIO buffer pairs on the top edge have true differential outputs. The sysIO buffer pair comprising of the A and B PIOs in every PIC on the top edge have a differential output driver. The referenced input buffer can also be configured as a differential input buffer.

### Typical I/O Behavior During Power-up

The internal power-on-reset (POR) signal is deactivated when  $V_{CC}$  and  $V_{CCIO0}$  have reached  $V_{PORUP}$  level defined in the Power-On-Reset Voltage table in the DC and Switching Characteristics section of this data sheet. After the POR signal is deactivated, the FPGA core logic becomes active. It is the user's responsibility to ensure that all  $V_{CCIO}$  banks are active with valid input logic levels to properly control the output logic states of all the I/O banks that are critical to the application. The default configuration of the I/O pins in a blank device is tri-state with a weak pulldown to GND (some pins such as PROGRAMN and the JTAG pins have weak pull-up to  $V_{CCIO}$  as the default functionality). The I/O pins will maintain the blank configuration until  $V_{CC}$  and  $V_{CCIO}$  (for I/O banks containing configuration I/Os) have reached  $V_{PORUP}$  levels at which time the I/Os will take on the user-configured settings only after a proper download/configuration.

### **Supported Standards**

The MachXO2 sysIO buffer supports both single-ended and differential standards. Single-ended standards can be further subdivided into LVCMOS, LVTTL, and PCI. The buffer supports the LVTTL, PCI, LVCMOS 1.2, 1.5, 1.8, 2.5, and 3.3 V standards. In the LVCMOS and LVTTL modes, the buffer has individually configurable options for drive strength, bus maintenance (weak pull-up, weak pull-down, bus-keeper latch or none) and open drain. BLVDS, MLVDS and LVPECL output emulation is supported on all devices. The MachXO2-640U, MachXO2-1200/U and higher devices support on-chip LVDS output buffers on approximately 50% of the I/Os on the top bank. Differential receivers for LVDS, BLVDS, MLVDS and LVPECL are supported on all banks of MachXO2 devices. PCI support is provided in the bottom bank of theMachXO2-640U, MachXO2-1200/U and higher density devices. Table 2-11 summarizes the I/O characteristics of the MachXO2 PLDs.

Tables 2-11 and 2-12 show the I/O standards (together with their supply and reference voltages) supported by the MachXO2 devices. For further information on utilizing the sysIO buffer to support a variety of standards please see TN1202, MachXO2 sysIO Usage Guide.



### Figure 2-20. Embedded Function Block Interface



## Hardened I<sup>2</sup>C IP Core

Every MachXO2 device contains two I<sup>2</sup>C IP cores. These are the primary and secondary I<sup>2</sup>C IP cores. Either of the two cores can be configured either as an I<sup>2</sup>C master or as an I<sup>2</sup>C slave. The only difference between the two IP cores is that the primary core has pre-assigned I/O pins whereas users can assign I/O pins for the secondary core.

When the IP core is configured as a master it will be able to control other devices on the  $I^2C$  bus through the interface. When the core is configured as the slave, the device will be able to provide I/O expansion to an  $I^2C$  Master. The  $I^2C$  cores support the following functionality:

- Master and Slave operation
- 7-bit and 10-bit addressing
- Multi-master arbitration support
- Up to 400 kHz data transfer speed
- General call support
- Interface to custom logic through 8-bit WISHBONE interface



## **Configuration and Testing**

This section describes the configuration and testing features of the MachXO2 family.

## IEEE 1149.1-Compliant Boundary Scan Testability

All MachXO2 devices have boundary scan cells that are accessed through an IEEE 1149.1 compliant test access port (TAP). This allows functional testing of the circuit board, on which the device is mounted, through a serial scan path that can access all critical logic nodes. Internal registers are linked internally, allowing test data to be shifted in and loaded directly onto test nodes, or test data to be captured and shifted out for verification. The test access port consists of dedicated I/Os: TDI, TDO, TCK and TMS. The test access port shares its power supply with V<sub>CCIO</sub> Bank 0 and can operate with LVCMOS3.3, 2.5, 1.8, 1.5, and 1.2 standards.

For more details on boundary scan test, see AN8066, Boundary Scan Testability with Lattice sysIO Capability and TN1087, Minimizing System Interruption During Configuration Using TransFR Technology.

## **Device Configuration**

All MachXO2 devices contain two ports that can be used for device configuration. The Test Access Port (TAP), which supports bit-wide configuration and the sysCONFIG port which supports serial configuration through I<sup>2</sup>C or SPI. The TAP supports both the IEEE Standard 1149.1 Boundary Scan specification and the IEEE Standard 1532 In-System Configuration specification. There are various ways to configure a MachXO2 device:

- 1. Internal Flash Download
- 2. JTAG
- 3. Standard Serial Peripheral Interface (Master SPI mode) interface to boot PROM memory
- 4. System microprocessor to drive a serial slave SPI port (SSPI mode)
- 5. Standard I<sup>2</sup>C Interface to system microprocessor

Upon power-up, the configuration SRAM is ready to be configured using the selected sysCONFIG port. Once a configuration port is selected, it will remain active throughout that configuration cycle. The IEEE 1149.1 port can be activated any time after power-up by sending the appropriate command through the TAP port. Optionally the device can run a CRC check upon entering the user mode. This will ensure that the device was configured correctly.

The sysCONFIG port has 10 dual-function pins which can be used as general purpose I/Os if they are not required for configuration. See TN1204, MachXO2 Programming and Configuration Usage Guide for more information about using the dual-use pins as general purpose I/Os.

Lattice design software uses proprietary compression technology to compress bit-streams for use in MachXO2 devices. Use of this technology allows Lattice to provide a lower cost solution. In the unlikely event that this technology is unable to compress bitstreams to fit into the amount of on-chip Flash memory, there are a variety of techniques that can be utilized to allow the bitstream to fit in the on-chip Flash memory. For more details, refer to TN1204, MachXO2 Programming and Configuration Usage Guide.

The Test Access Port (TAP) has five dual purpose pins (TDI, TDO, TMS, TCK and JTAGENB). These pins are dual function pins - TDI, TDO, TMS and TCK can be used as general purpose I/O if desired. For more details, refer to TN1204, MachXO2 Programming and Configuration Usage Guide.

### TransFR (Transparent Field Reconfiguration)

TransFR is a unique Lattice technology that allows users to update their logic in the field without interrupting system operation using a simple push-button solution. For more details refer to TN1087, Minimizing System Interruption During Configuration Using TransFR Technology for details.



## RSDS

The MachXO2 family supports the differential RSDS standard. The output standard is emulated using complementary LVCMOS outputs in conjunction with resistors across the driver outputs on all the devices. The RSDS input standard is supported by the LVDS differential input buffer. The scheme shown in Figure 3-4 is one possible solution for RSDS standard implementation. Use LVDS25E mode with suggested resistors for RSDS operation. Resistor values in Figure 3-4 are industry standard values for 1% resistors.



### Figure 3-4. RSDS (Reduced Swing Differential Standard)

#### Table 3-4. RSDS DC Conditions

Parameter	Description	Typical	Units
Z <sub>OUT</sub>	Output impedance	20	Ohms
R <sub>S</sub>	Driver series resistor	294	Ohms
R <sub>P</sub>	Driver parallel resistor	121	Ohms
R <sub>T</sub>	Receiver termination	100	Ohms
V <sub>OH</sub>	Output high voltage	1.35	V
V <sub>OL</sub>	Output low voltage	1.15	V
V <sub>OD</sub>	Output differential voltage	0.20	V
V <sub>CM</sub>	Output common mode voltage	1.25	V
Z <sub>BACK</sub>	Back impedance	101.5	Ohms
IDC	DC output current	3.66	mA



## Typical Building Block Function Performance – ZE Devices<sup>1</sup>

## Pin-to-Pin Performance (LVCMOS25 12 mA Drive)

Function	–3 Timing	Units
Basic Functions		
16-bit decoder	13.9	ns
4:1 MUX	10.9	ns
16:1 MUX	12.0	ns

### **Register-to-Register Performance**

–3 Timing	Units
191	MHz
134	MHz
148	MHz
77	MHz
90	MHz
214	MHz
	191 134 148 77 90

1. The above timing numbers are generated using the Diamond design tool. Exact performance may vary with device and tool version. The tool uses internal parameters that have been characterized but are not tested on every device.

## **Derating Logic Timing**

Logic timing provided in the following sections of the data sheet and the Lattice design tools are worst case numbers in the operating range. Actual delays may be much faster. Lattice design tools can provide logic timing numbers at a particular temperature and voltage.



#### Figure 3-9. GDDR71 Video Timing Waveforms



Figure 3-10. Receiver GDDR71\_RX. Waveforms



Figure 3-11. Transmitter GDDR71\_TX. Waveforms





## MachXO2 Oscillator Output Frequency

Symbol	Parameter	Min.	Тур.	Max	Units
f	Oscillator Output Frequency (Commercial Grade Devices, 0 to 85°C)		133	140.315	MHz
f <sub>MAX</sub>	Oscillator Output Frequency (Industrial Grade Devices, –40 °C to 100 °C)	124.355	133	141.645	MHz
t <sub>DT</sub>	Output Clock Duty Cycle	43	50	57	%
t <sub>OPJIT</sub> 1	Output Clock Period Jitter	0.01	0.012	0.02	UIPP
t <sub>STABLEOSC</sub>	STDBY Low to Oscillator Stable	0.01	0.05	0.1	μs

1. Output Clock Period Jitter specified at 133 MHz. The values for lower frequencies will be smaller UIPP. The typical value for 133 MHz is 95 ps and for 2.08 MHz the typical value is 1.54 ns.

## MachXO2 Standby Mode Timing – HC/HE Devices

Symbol	Parameter	Device	Min.	Тур.	Max	Units
t <sub>PWRDN</sub>	USERSTDBY High to Stop	All	_	_	9	ns
		LCMXO2-256		_		μs
		LCMXO2-640		_		μs
		LCMXO2-640U		_		μs
t <sub>PWRUP</sub>		LCMXO2-1200	20	_	50	μs
	USERSTDBY Low to Power Up	LCMXO2-1200U				μs
		LCMXO2-2000		_		μs
		LCMXO2-2000U		_		μs
		LCMXO2-4000		_		μs
		LCMXO2-7000		_		μs
t <sub>WSTDBY</sub>	USERSTDBY Pulse Width	All	18		—	ns



## MachXO2 Standby Mode Timing – ZE Devices

Symbol	Parameter	Device	Min.	Тур.	Max	Units
t <sub>PWRDN</sub>	USERSTDBY High to Stop	All	_	—	13	ns
		LCMXO2-256		—		μs
		LCMXO2-640		—		μs
+	USERSTDBY Low to Power Up	LCMXO2-1200	20	—	50	μs
<sup>t</sup> PWRUP		LCMXO2-2000		—		μs
		LCMXO2-4000		—		μs
		LCMXO2-7000		_		μs
t <sub>WSTDBY</sub>	USERSTDBY Pulse Width	All	19			ns
t <sub>BNDGAPSTBL</sub>	USERSTDBY High to Bandgap Stable	All		—	15	ns



	MachXO2-4000							
	84 QFN	132 csBGA	144 TQFP	184 csBGA	256 caBGA	256 ftBGA	332 caBGA	484 fpBGA
General Purpose I/O per Bank								
Bank 0	27	25	27	37	50	50	68	70
Bank 1	10	26	29	37	52	52	68	68
Bank 2	22	28	29	39	52	52	70	72
Bank 3	0	7	9	10	16	16	24	24
Bank 4	9	8	10	12	16	16	16	16
Bank 5	0	10	10	15	20	20	28	28
Total General Purpose Single Ended I/O	68	104	114	150	206	206	274	278
Differential I/O per Bank								
Bank 0	13	13	14	18	25	25	34	35
Bank 1	4	13	14	18	26	26	34	34
Bank 2	11	14	14	19	26	26	35	36
Bank 3	0	3	4	4	8	8	12	12
Bank 4	4	4	5	6	8	8	8	8
Bank 5	0	5	5	7	10	10	14	14
Total General Purpose Differential I/O	32	52	56	72	103	103	137	139
Dual Function I/O	28	37	37	37	37	37	37	37
High-speed Differential I/O				•				
Bank 0	8	8	9	8	18	18	18	18
Gearboxes				•				
Number of 7:1 or 8:1 Output Gearbox Available (Bank 0)	8	8	9	9	18	18	18	18
Number of 7:1 or 8:1 Input Gearbox Available (Bank 2)	11	14	14	12	18	18	18	18
DQS Groups	1	1						
Bank 1	1	2	2	2	2	2	2	2
VCCIO Pins								
Bank 0	3	3	3	3	4	4	4	10
Bank 1	1	3	3	3	4	4	4	10
Bank 2	2	3	3	3	4	4	4	10
Bank 3	1	1	1	1	1	1	2	3
Bank 4	1	1	1	1	2	2	1	4
Bank 5	1	1	1	1	1	1	2	3
VCC	4	4	4	4	8	8	8	12
GND	4	10	12	16	24	24	27	48
NC	1	1	1	1	1	1	5	105
Reserved for configuration	1	1	1	1	1	1	1	1
liebel ved for bernigaration								



## **For Further Information**

For further information regarding logic signal connections for various packages please refer to the MachXO2 Device Pinout Files.

## **Thermal Management**

Thermal management is recommended as part of any sound FPGA design methodology. To assess the thermal characteristics of a system, Lattice specifies a maximum allowable junction temperature in all device data sheets. Users must complete a thermal analysis of their specific design to ensure that the device and package do not exceed the junction temperature limits. Refer to the Thermal Management document to find the device/package specific thermal values.

## For Further Information

For further information regarding Thermal Management, refer to the following:

- Thermal Management document
- TN1198, Power Estimation and Management for MachXO2 Devices
- The Power Calculator tool is included with the Lattice design tools, or as a standalone download from www.latticesemi.com/software



# MachXO2 Family Data Sheet Ordering Information

March 2017

Data Sheet DS1035

## MachXO2 Part Number Description



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## **Ordering Information**

MachXO2 devices have top-side markings, for commercial and industrial grades, as shown below:



Notes:

- 1. Markings are abbreviated for small packages.
- 2. See PCN 05A-12 for information regarding a change to the top-side mark logo.



Part Number	LUTs	Supply Voltage	Grade	Package	Leads	Temp.
LCMXO2-4000HE-6BG332C	4320	1.2 V	-6	Halogen-Free caBGA	332	COM
LCMXO2-4000HE-4FG484C	4320	1.2 V	-4	Halogen-Free fpBGA	484	COM
LCMXO2-4000HE-5FG484C	4320	1.2 V	-5	Halogen-Free fpBGA	484	COM
LCMXO2-4000HE-6FG484C	4320	1.2 V	-6	Halogen-Free fpBGA	484	COM

Part Number	LUTs	Supply Voltage	Grade	Package	Leads	Temp.
LCMXO2-7000HE-4TG144C	6864	1.2 V	-4	Halogen-Free TQFP	144	COM
LCMXO2-7000HE-5TG144C	6864	1.2 V	-5	Halogen-Free TQFP	144	COM
LCMXO2-7000HE-6TG144C	6864	1.2 V	-6	Halogen-Free TQFP	144	COM
LCMXO2-7000HE-4BG256C	6864	1.2 V	-4	Halogen-Free caBGA	256	COM
LCMXO2-7000HE-5BG256C	6864	1.2 V	-5	Halogen-Free caBGA	256	COM
LCMXO2-7000HE-6BG256C	6864	1.2 V	-6	Halogen-Free caBGA	256	COM
LCMXO2-7000HE-4FTG256C	6864	1.2 V	-4	Halogen-Free ftBGA	256	COM
LCMXO2-7000HE-5FTG256C	6864	1.2 V	-5	Halogen-Free ftBGA	256	COM
LCMXO2-7000HE-6FTG256C	6864	1.2 V	-6	Halogen-Free ftBGA	256	COM
LCMXO2-7000HE-4BG332C	6864	1.2 V	-4	Halogen-Free caBGA	332	COM
LCMXO2-7000HE-5BG332C	6864	1.2 V	-5	Halogen-Free caBGA	332	COM
LCMXO2-7000HE-6BG332C	6864	1.2 V	-6	Halogen-Free caBGA	332	COM
LCMXO2-7000HE-4FG484C	6864	1.2 V	-4	Halogen-Free fpBGA	484	COM
LCMXO2-7000HE-5FG484C	6864	1.2 V	-5	Halogen-Free fpBGA	484	COM
LCMXO2-7000HE-6FG484C	6864	1.2 V	-6	Halogen-Free fpBGA	484	COM



Part Number	LUTs	Supply Voltage	Grade	Package	Leads	Temp.
LCMXO2-1200HC-4TG100IR11	1280	2.5 V / 3.3 V	-4	Halogen-Free TQFP	100	IND
LCMXO2-1200HC-5TG100IR11	1280	2.5 V / 3.3 V	-5	Halogen-Free TQFP	100	IND
LCMXO2-1200HC-6TG100IR11	1280	2.5 V / 3.3 V	-6	Halogen-Free TQFP	100	IND
LCMXO2-1200HC-4MG132IR11	1280	2.5 V / 3.3 V	-4	Halogen-Free csBGA	132	IND
LCMXO2-1200HC-5MG132IR1 <sup>1</sup>	1280	2.5 V / 3.3 V	-5	Halogen-Free csBGA	132	IND
LCMXO2-1200HC-6MG132IR1 <sup>1</sup>	1280	2.5 V / 3.3 V	-6	Halogen-Free csBGA	132	IND
LCMXO2-1200HC-4TG144IR11	1280	2.5 V / 3.3 V	-4	Halogen-Free TQFP	144	IND
LCMXO2-1200HC-5TG144IR1 <sup>1</sup>	1280	2.5 V / 3.3 V	-5	Halogen-Free TQFP	144	IND
LCMXO2-1200HC-6TG144IR11	1280	2.5 V / 3.3 V	-6	Halogen-Free TQFP	144	IND

1. Specifications for the "LCMXO2-1200HC-speed package IR1" are the same as the "LCMXO2-1200ZE-speed package I" devices respectively, except as specified in the R1 Device Specifications section of this data sheet.



Date	Version	Section	Change Summary		
December 2014	2.9	Introduction	Updated the Features section. Revised Table 1-1, MachXO2 Family Selection Guide. — Removed XO2-4000U data. — Removed 400-ball ftBGA. — Removed 25-ball WLCSP value for XO2-2000U.		
	DC and Switching Characteristics	Updated the Recommended Operating Conditions section. Adjusted Max. values for $V_{CC}$ and $V_{CCIO}.$			
		Updated the sysIO Recommended Operating Conditions section. Adjusted Max. values for LVCMOS 3.3, LVTTL, PCI, LVDS33 and LVPECL.			
		Pinout Information	Updated the Pinout Information Summary section. Removed MachXO2-4000U.		
	Ordering Information	Updated the MachXO2 Part Number Description section. Removed BG400 package.			
			Updated the High-Performance Commercial Grade Devices with Volt- age Regulator, Halogen Free (RoHS) Packaging section. Removed LCMXO2-4000UHC part numbers.		
			Updated the High-Performance Industrial Grade Devices with Voltage Regulator, Halogen Free (RoHS) Packaging section. Removed LCMXO2-4000UHC part numbers.		
November 2014 2.8	2.8	Introduction	Updated the Features section. — Revised I/Os under Flexible Logic Architecture. — Revised standby power under Ultra Low Power Devices. — Revise input frequency range under Flexible On-Chip Clocking.		
		Updated Table 1-1, MachXO2 Family Selection Guide. — Added XO2-4000U data. — Removed HE and ZE device options for XO2-4000. — Added 400-ball ftBGA.			
		Pinout Information	Updated the Pinout Information Summary section. Added MachXO2-4000U caBGA400 and MachXO2-7000 caBGA400.		
		Ordering Information	Updated the MachXO2 Part Number Description section. Added BG400 package.		
			Updated the Ordering Information section. Added MachXO2-4000U caBGA400 and MachXO2-7000 caBGA400 part numbers.		
October 2014 2.7	2.7	Ordering Information	Updated the Ultra Low Power Industrial Grade Devices, Halogen Free (RoHS) Packaging section. Fixed typo in LCMXO2-2000ZE- 1UWG49ITR part number package.		
		Architecture	Updated the Supported Standards section. Added MIPI information to Table 2-12. Supported Input Standards and Table 2-13. Supported Output Standards.		
	DC and Switching Characteristics	Updated the BLVDS section. Changed output impedance nominal values in Table 3-2, BLVDS DC Condition.			
		Updated the LVPECL section. Changed output impedance nominal value in Table 3-3, LVPECL DC Condition.			
		Updated the sysCONFIG Port Timing Specifications section. Updated INITN low time values.			
July 2014 2.6	2.6	DC and Switching Characteristics	Updated sysIO Single-Ended DC Electrical Characteristics <sup>1, 2</sup> section. Updated footnote 4.		
			Updated Register-to-Register Performance section. Updated foot- note.		
		Ordering Information	Updated UW49 package to UWG49 in MachXO2 Part Number Description.		
			Updated LCMXO2-2000ZE-1UWG49CTR package in Ultra Low Power Commercial Grade Devices, Halogen Free (RoHS) Packaging.		



Date	Version	Section	Change Summary		
February 2012	01.7	All	Updated document with new corporate logo.		
01.6	01.6	—	Data sheet status changed from preliminary to final.		
	Introduction	MachXO2 Family Selection Guide table – Removed references to 49-ball WLCSP.			
	DC and Switching Characteristics	Updated Flash Download Time table.			
		Modified Storage Temperature in the Absolute Maximum Ratings section.			
			Updated I <sub>DK</sub> max in Hot Socket Specifications table.		
			Modified Static Supply Current tables for ZE and HC/HE devices.		
			Updated Power Supply Ramp Rates table.		
			Updated Programming and Erase Supply Current tables.		
			Updated data in the External Switching Characteristics table.		
			Corrected Absolute Maximum Ratings for Dedicated Input Voltage Applied for LCMXO2 HC.		
			DC Electrical Characteristics table – Minor corrections to conditions for $\mathbf{I}_{IL},  \mathbf{I}_{IH.}$		
		Pinout Information	Removed references to 49-ball WLCSP.		
			Signal Descriptions table – Updated description for GND, VCC, and VCCIOx.		
			Updated Pin Information Summary table – Number of VCCIOs, GNDs, VCCs, and Total Count of Bonded Pins for MachXO2-256, 640, and 640U and Dual Function I/O for MachXO2-4000 332caBGA.		
		Ordering Information	Removed references to 49-ball WLCSP		
August 2011	01.5	DC and Switching Characteristics	Updated ESD information.		
		Ordering Information	Updated footnote for ordering WLCSP devices.		
	01.4	Architecture	Updated information in Clock/Control Distribution Network and sys- CLOCK Phase Locked Loops (PLLs).		
		DC and Switching Characteristics	Updated ${\rm I}_{\rm IL}$ and ${\rm I}_{\rm IH}$ conditions in the DC Electrical Characteristics table.		
		Pinout Information	Included number of 7:1 and 8:1 gearboxes (input and output) in the pin information summary tables.		
		Updated Pin Information Summary table: Dual Function I/O, DQS Groups Bank 1, Total General Purpose Single-Ended I/O, Differential I/O Per Bank, Total Count of Bonded Pins, Gearboxes.			
		Added column of data for MachXO2-2000 49 WLCSP.			
	Ordering Information	Updated R1 Device Specifications text section with information on migration from MachXO2-1200-R1 to Standard (non-R1) devices.			
		Corrected Supply Voltage typo for part numbers: LCMX02-2000UHE- 4FG484I, LCMX02-2000UHE-5FG484I, LCMX02-2000UHE- 6FG484I.			
			Added footnote for WLCSP package parts.		
		Supplemental Information	Removed reference to Stand-alone Power Calculator for MachXO2 Devices. Added reference to AN8086, Designing for Migration from MachXO2-1200-R1 to Standard (non-R1) Devices.		



Date	Version	Section	Change Summary		
May 2011	01.3 Multiple		Replaced "SED" with "SRAM CRC Error Detection" throughout the document.		
		DC and Switching Characteristics	Added footnote 1 to Program Erase Specifications table.		
		Pinout Information	Updated Pin Information Summary tables.		
			Signal name SO/SISPISO changed to SO/SPISO in the Signal Descriptions table.		
April 2011	01.2	_	Data sheet status changed from Advance to Preliminary.		
		Introduction	Updated MachXO2 Family Selection Guide table.		
		Architecture	Updated Supported Input Standards table.		
			Updated sysMEM Memory Primitives diagram.		
			Added differential SSTL and HSTL IO standards.		
	DC and Switching Characteristics	Updates following parameters: POR voltage levels, DC electrical characteristics, static supply current for ZE/HE/HC devices, static power consumption contribution of different components – ZE devices, programming and erase Flash supply current.			
			Added VREF specifications to sysIO recommended operating condi- tions.		
			Updating timing information based on characterization.		
			Added differential SSTL and HSTL IO standards.		
		Ordering Information	Added Ordering Part Numbers for R1 devices, and devices in WLCSP packages.		
			Added R1 device specifications.		
January 2011	01.1	All	Included ultra-high I/O devices.		
		DC and Switching Characteristics	Recommended Operating Conditions table – Added footnote 3.		
			DC Electrical Characteristics table – Updated data for $\rm I_{IL},  I_{IH},  V_{HYST}$ typical values updated.		
		Generic DDRX2 Outputs with Clock and Data Aligned at Pin (GDDRX2_TX.ECLK.Aligned) Using PCLK Pin for Clock Input tables – Updated data for $T_{DIA}$ and $T_{DIB}$ .			
		Generic DDRX4 Outputs with Clock and Data Aligned at Pin (GDDRX4_TX.ECLK.Aligned) Using PCLK Pin for Clock Input tables – Updated data for $T_{DIA}$ and $T_{DIB}$ .			
			Power-On-Reset Voltage Levels table - clarified note 3.		
		Clarified VCCIO related recommended operating conditions specifications.			
		Added power supply ramp rate requirements.			
		Added Power Supply Ramp Rates table.			
		Updated Programming/Erase Specifications table.			
		Removed references to V <sub>CCP.</sub>			
		Pinout Information	Included number of 7:1 and 8:1 gearboxes (input and output) in the pin information summary tables.		
			Removed references to V <sub>CCP.</sub>		
November 2010	01.0	—	Initial release.		